

Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



General Product Information

Product	Application
935 nm DFB Laser	Spectroscopy
with hermetic 8-Pin TO Package (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-20		75
Operational Temperature at Laser Chip	T_LD	°C	5		45
Forward Current	I _F	mA			200
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	mW			90
TEC Current	I_{TEC}	А			1.8
TEC Voltage	V_{TEC}	V			3.2

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	-20		65
Operational Temperature at Laser Chip	T_LD	°C	15		40
Forward Current	I _F	mA			180
Output Power	P _{opt}	mW	20		80

Measurement	Conditions /	Comments

measured by integrated Thermistor

Characteristics at T_{LD} = 25° at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	934	935	937
Target Wavelength	λ_{T}	nm		935.7	
Linewidth (FWHM)	$\Delta\lambda$	MHz		0.6	1
Sidemode Supression Ratio	SMSR	dB	30	45	
Temperature Coefficient of Wavelength	$d\lambda/dT$	nm / K		0.06	
Current Coefficient of Wavelength	$d\lambda/dI$	nm / mA		0.003	
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	100		

weasurement Condition	s / Comments
see images on page 4	
reached within $T_{LD} =$	0 ° 45° C at 80 mW
$P_{opt} = 80 \text{ mW}$	
at target wavelength	

© All rights reserved by eagleyard Photonics GmbH. This data sheet will be electronically administered and is subject to change without notice. Uncontrolled copy when printed.





Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



Characteristics at T _{LD} = 25°	at BOL				cont'd
Parameter	Symbol	Unit	min	tvn	max
raiailletei	Зуппоот	OIIIL	111111	typ	
Laser Current @ P _{opt} = 80 mW	I_{LD}	mΑ			180
Slope Efficiency	η	W/A	0.5	0.8	1.0
Threshold Current	I _{th}	mA			70
Divergence parallel (FWHM)	$\Theta_{ }$	0		8	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		21	
Degree of Polarization	DOP	%		90	

Measurement Conditions / Comments
parallel to short axis of the housing (see p. 3)
parallel to long axis of the housing (see p. 3)
80 mW; E field parallel to short axis of housing

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	μΑ/mW	1		20

Meası	urement Conditions / Comments
$J_R =$	5 V

Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		0.8	
Power Dissipation (total loss at case)	P _{loss}	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments				
$P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$				
$P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$				
$P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$				
$P_{opt} = 80 \text{ mW}, \Delta T = Tcase - TLD $				

Parameter	Symbol	Unit	min	typ	max	
Resistance	R	kΩ		10		
Beta Coefficient	β			3892		
Steinhart & Hart Coefficient A	А		1.1293 x 10 ⁻³			
Steinhart & Hart Coefficient B	В		2.3410 x 10 ⁻⁴			
Steinhart & Hart Coefficient C	C			3.7755 x 10	-8	

Measurement Conditions / Comments						
$T_{LD} = 25^{\circ} C$						
$R_1/R_2 = e^{\beta(1/T_1-1/T_2)}$ at $T_{LD} =$	0° 50° C					
$1/T = A + B(\ln R) + C(\ln R)^3$						
T: temperature in Kelvin						
R: resistance at T in Ohm						



Thermistor (Standard NTC Type)

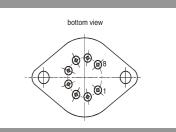


Revision 0.94

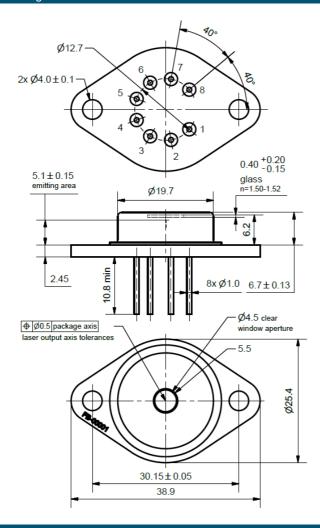
SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

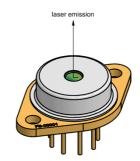


Pi	n Assignment		
1	The arrange of a string Condon ()	5	Laser Diode Anode
1	Thermoelectric Cooler (+)	5	Laser Diode Anode
2	Thermistor	6	Monitor Diode Anode
3	Thermistor	7	Photo Diode Cathode
4	Laser Diode Cathode	8	Thermoelectric Cooler (-)
All	8 pins are isolated from case.		



Package Drawings





AIZ-16-311-1543-B



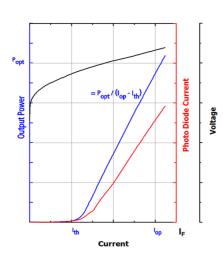
Revision 0.94

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

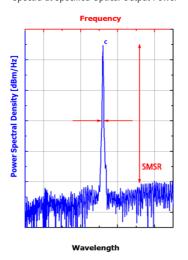


Typical Measurement Results

Output Power vs. Current



Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Ordering Information:



800 Village Walk #316 Guilford, CT 06437 Ph: 203-401-8093

Email orders to: sales@xsoptix.com
Fax orders to: 800-878-7282

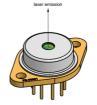
Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.







INVISIBLE LASER RADIATION
AVOID EVE OR SKIM EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 935 nm
MAX. OUTPUT POWER 90 mW





